NSN 5961-00-878-8529

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-878-8529 **Inclosure Material:** Metal **Overall Length:** 2.500 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.047 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakover voltage, dc **Current Rating Per Characteristic:** 70.00 amperes source cutoff current **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 threaded stud **Specification Data:** 80131-release3317 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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